L Number	Hits	Search Text	DB	Time stamp
1	810487	memory	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:33
2	13948	memory and condition with cell	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:33
3	421	(memory and condition with cell) and (alter$4 or adjust$4) with eras$4	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:35
4	92	((memory and condition with cell) and (alter$4 or adjust$4) with eras$4) and off with eras$4 with cell	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:35
5	14	(((memory and condition with cell) and (alter$4 or adjust$4) with eras$4) and off with eras$4 with cell) and off with (over-eras$3 or over$4 adj eras$4) with cell	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:39
6	10	((((memory and condition with cell) and (alter$4 or adjust$4) with eras$4) and off with eras$4 with cell) and off with (over-eras$3 or over$4 adj eras$4) with cell) and (bit or bitline) near3 current	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:37
7	10	(((memory and condition with cell) and (alter$4 or adjust$4) with eras$4) and off with eras$4 with cell) and off with (over-eras$3 or over$4 adj eras$4) with cell with (voltage or potential)	USPAT; US-PGPUB; EPO; JPO	2002/10/21 10:41